



BC 485

BC 487

BC 489

NPN SILICON PLANAR EPITAXIAL TRANSISTORS

MICRO ELECTRONICS

BC485, BC487 and BC489 are NPN silicon planar epitaxial transistors designed for use as high voltage high current driver and output transistors.

CASE TO-92FCBEABSOLUTE MAXIMUM RATINGS

		BC485	BC487	BC489
Collector-Base Voltage	V <sub>CB0</sub>	45V	60V	80V
Collector-Emitter Voltage	V <sub>C EO</sub>	45V	60V	80V
Emitter-Base Voltage	V <sub>E BO</sub>		5V	
Collector Current	I <sub>C</sub>		1A	
Total Power Dissipation @ T <sub>A</sub> =25°C @ T <sub>C</sub> =25°C	P <sub>tot</sub>		625mW 1.5W	
Operating Junction & Storage Temperature	T <sub>j</sub> , T <sub>stg</sub>		-55 to +150°C	

ELECTRICAL CHARACTERISTICS AT T<sub>A</sub>=25°C

PARAMETER	SYMBOL	MIN	TYP	MAX	UNIT	TEST CONDITIONS
Collector-Base Breakdown Voltage	BVCBO				V	I <sub>C</sub> =0.1mA I <sub>E</sub> =0
Collector-Emitter Breakdown Voltage	BVCEO	Note 1			V	I <sub>C</sub> =10mA I <sub>B</sub> =0
Emitter-Base Breakdown Voltage	BVEBO				V	I <sub>E</sub> =10μA I <sub>C</sub> =0
Collector Cutoff Current	I <sub>CBO</sub>		100	nA	V <sub>CB</sub> =V <sub>CB0</sub>	I <sub>E</sub> =0
Collector-Emitter Saturation Voltage	V <sub>CE(SAT)</sub> *		0.5	V	I <sub>C</sub> =500mA I <sub>B</sub> =50mA	
Base-Emitter Saturation Voltage	V <sub>BE(SAT)</sub> *		1.2	V	I <sub>C</sub> =500mA I <sub>B</sub> =50mA	
D.C. Current Gain All groups	HFE*	40				I <sub>C</sub> =10mA V <sub>CE</sub> =2V
All groups		60	400			I <sub>C</sub> =100mA V <sub>CE</sub> =2V
Group L		60	150			I <sub>C</sub> =100mA V <sub>CE</sub> =2V
Group A		100	250			I <sub>C</sub> =100mA V <sub>CE</sub> =2V
Group B		160	400			I <sub>C</sub> =100mA V <sub>CE</sub> =2V
All groups		15				I <sub>C</sub> =1A V <sub>CE</sub> =5V
Current Gain-Bandwidth Product	f <sub>T</sub>		75	MHz	I <sub>C</sub> =50mA	V <sub>CE</sub> =2V
Output Capacitance	C <sub>ob</sub>		12	pF	V <sub>CB</sub> =10V	I <sub>E</sub> =0
Input Capacitance	C <sub>ib</sub>		85	pF	V <sub>BE</sub> =2V	I <sub>C</sub> =0

Note 1 : equal to the values of the absolute maximum ratings.

\* Pulse Test : Pulse Width=0.3ms, Duty Cycle=1%

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